

TD62705P, TD62705F, TD62706P, TD62706F

6CH HIGH-VOLTAGE SOURCE DRIVER

The TD62705P, TD62705F and TD62706P, TD62706F are comprised of six source current transistor array.

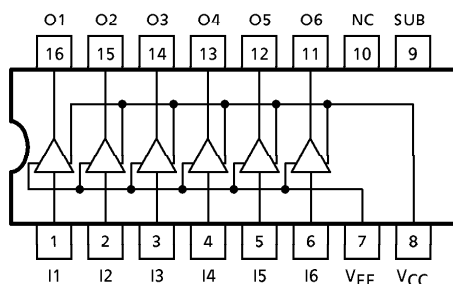
These drivers are specifically designed for fluorescent display applications.

For proper operation, the substrate (SUB) must be connected to the most negative voltage.

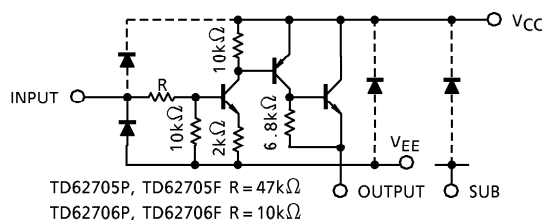
FEATURES

- High output voltage : $V_{CC} - V_{OUT} = 60V$ (Min.)
- Output current (single output) : $I_{OUT} = -50mA$ (Max.)
- Input compatible with various types of logic
 TD62705P, TD62705F $R_{IN} = 47k\Omega$: 6~25V PMOS, CMOS
 TD62706P, TD62706F $R_{IN} = 10k\Omega$: TTL, 5V CMOS
- Package type-P : DIP-16 pin
- Package type-F : SOP-16 pin

PIN CONNECTION (TOP VIEW)



SCHEMATICS (EACH DRIVER)



(Note) The input and output parasitic diodes cannot be used as clamp diodes.

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MAXIMUM RATINGS ($T_a = 25^\circ\text{C}$)

CHARACTERISTIC		SYMBOL	RATING	UNIT
Supply Voltage		$V_{CC}-V_{EE}$	30	V
		$V_{CC}-V_{SUB}$	60	
Output Voltage		$V_{CC}-V_{OUT}$	- 60	V
Input Voltage		$V_{IN}-V_{EE}$	$V_{CC}-V_{EE}$	V
Output Current		I_{OUT}	- 50	mA / ch
Input Current		I_{IN}	± 10	mA
Power Dissipation	P	P_D (Note 2)	1.0	W
	F		0.625 (Note 1)	
Operating Temperature		T_{opr}	- 40~85	$^\circ\text{C}$
Storage Temperature		T_{stg}	- 55~150	$^\circ\text{C}$

(Note 1) On Glass Epoxy PCB (30×30×1.6mm Cu 50%)

(Note 2) Delated above 25°C in the proportion of 8.0mw/°C (P Type), 5.0mw/°C (F Type).

RECOMMENDED OPERATING CONDITIONS ($T_a = -40\sim 85^\circ\text{C}$)

CHARACTERISTIC		SYMBOL	CONDITION	MIN.	TYP.	MAX.	UNIT
Supply Voltage	TD62705P TD62705F	V_{CC}	$V_{EE} = 0V$	6.0	—	25	V
	TD62706P TD62706F			4.5	—	25	
		V_{SUB}	$V_{CC} = 0V$	V_{OUT}	—	- 55	V
Output Voltage		V_{OUT}	$V_{CC} = 0V$	0	—	- 55	V
Output Current		I_{OUT}	—	0	—	- 40	mA / ch
Input Voltage	TD62705P TD62705F	V_{IN}	$V_{EE} = 0V, V_{CC} = 25V$	0	—	25	V
	TD62706P TD62706F			0	—	7	
Power Dissipation	P	P_D	—	—	—	0.36	W
	F		On PCB (Note)	—	—	0.325	

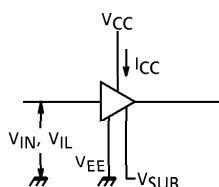
(Note) On Glass Epoxy PCB (30×30×1.6mm, Cu 50%)

ELECTRICAL CHARACTERISTICS (Ta = 25°C)

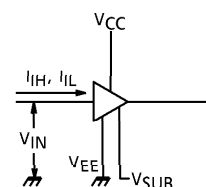
CHARACTERISTIC			SYMBOL	TEST CIR- CUIT	TEST CONDITION	MIN.	TYP.	MAX.	UNIT
Input Voltage	“H” Level	TD62705P	V _{IH}	1	V _{EE} = 0V	6.0	—	—	V
		TD62705F			V _{EE} = 0V	2.2	—	—	
	“L” Level	TD62706P	V _{IL}	1	V _{EE} = 0V	—	—	2.2	
		TD62706F			V _{EE} = 0V	—	—	0.8	
Input Current	“H” Level	TD62705P	I _{IH}	2	V _{EE} = 0V, V _{IN} = 6.0V	—	0.11	0.16	mA
		TD62705F			V _{EE} = 0V, V _{IN} = 2.4V	—	0.12	0.18	
	“L” Level		I _{IL}	2	V _{EE} = V _{IN} = 0V, V _{CC} = 25V	—	—	± 1	μA
Output Leakage Current			I _{CEX}	3	V _{EE} = 0V, V _{CC} = 25V V _{IN} = V _{IL} MAX. I _{OUT} = – 30V	—	—	– 100	μA
Collector-Emitter Saturation Voltage			V _{CE} (sat)	4	V _{EE} = 0V, V _{CC} = V _{CC} MIN. V _{IN} = V _{IH} MIN. I _{OUT} = – 40mA	—	—	V _{CC} – 2.5	V
Supply Current (Output On)		TD62705P	I _{CC}	1	V _{EE} = 0V, V _{CC} = 25V V _{IN} = V _{IN} MAX. I _{OUT} = 0mA	—	—	32	mA
		TD62706P				—	—	25	
Turn-On Delay			t _{ON}	5	R _L = 1.4kΩ, C _L = 15pF	—	0.2	—	μs
Turn-Off Delay			t _{OFF}			—	1.5	—	μs

TEST CIRCUIT

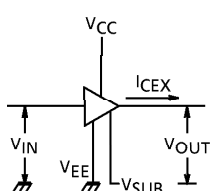
1. V_{IH} , V_{IL} , I_{CC}



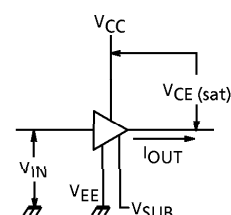
2. I_{IH} , I_{IL}



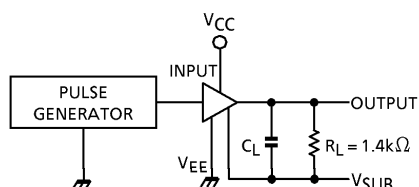
3. I_{CEX}



4. $V_{CE(sat)}$



5. t_{ON} , t_{OFF}



$C_L = 15\text{pF}$
(Includes probe and jig capacitance)

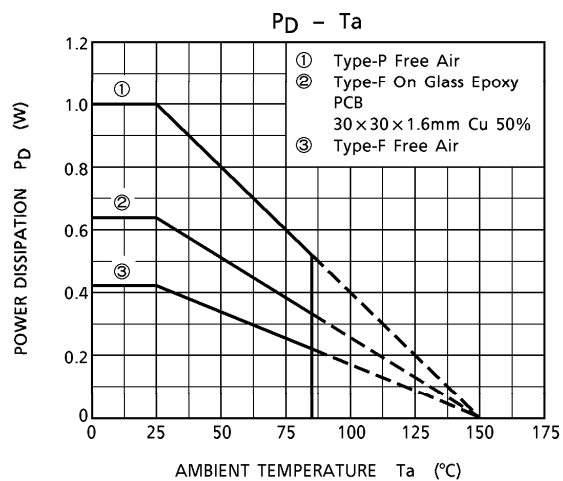
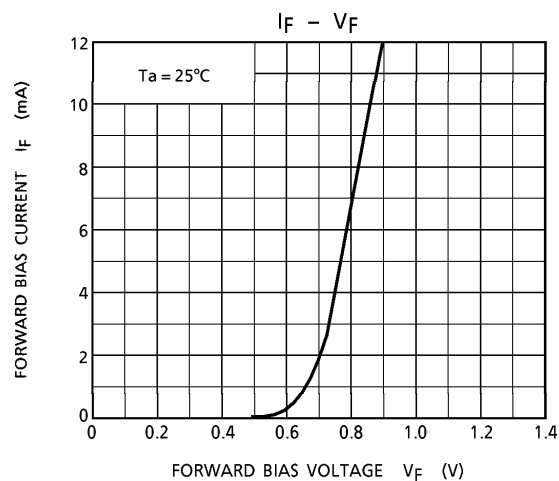
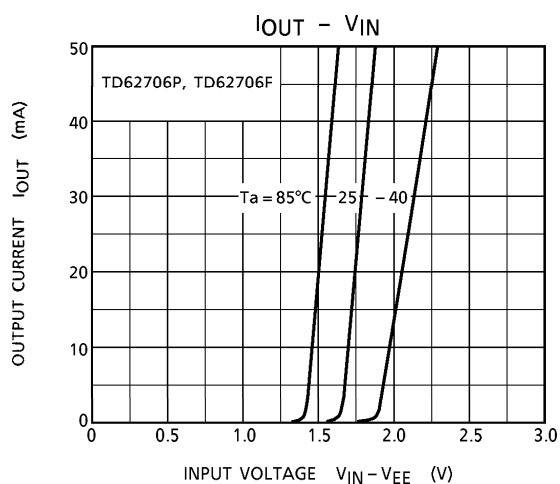
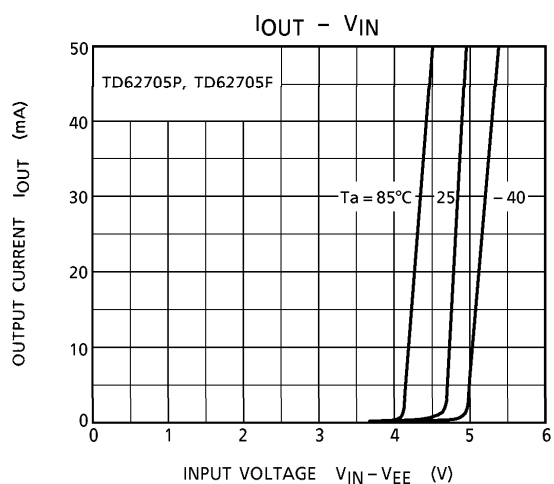
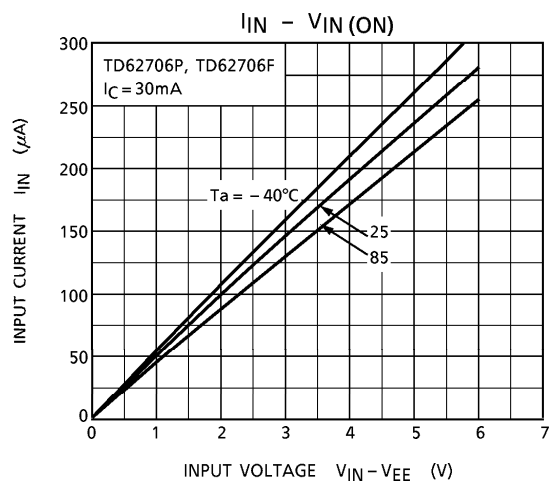
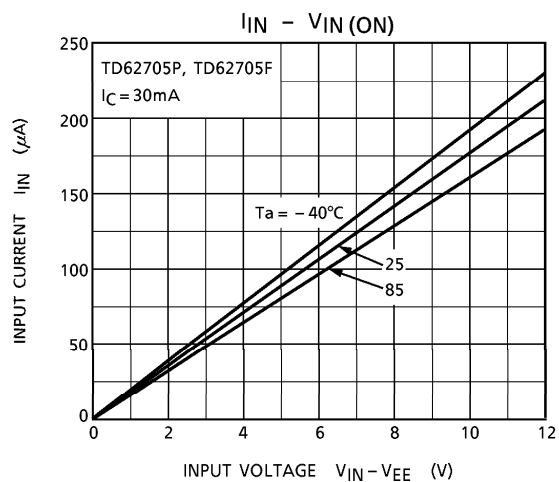
INPUT CONDITION

TYPE NAME	V_{IN}	V_{CC}	V_{SUB}
TD62705P, TD62705F	0-9V	25V	-30
TD62706P, TD62706F	0-3V	25V	-30

V_{IN} : Pulse Width $50\mu\text{s}$
Duty Cycle 50%
 $t_r \leq 5\text{ns}$
 $t_f \leq 10\text{ns}$

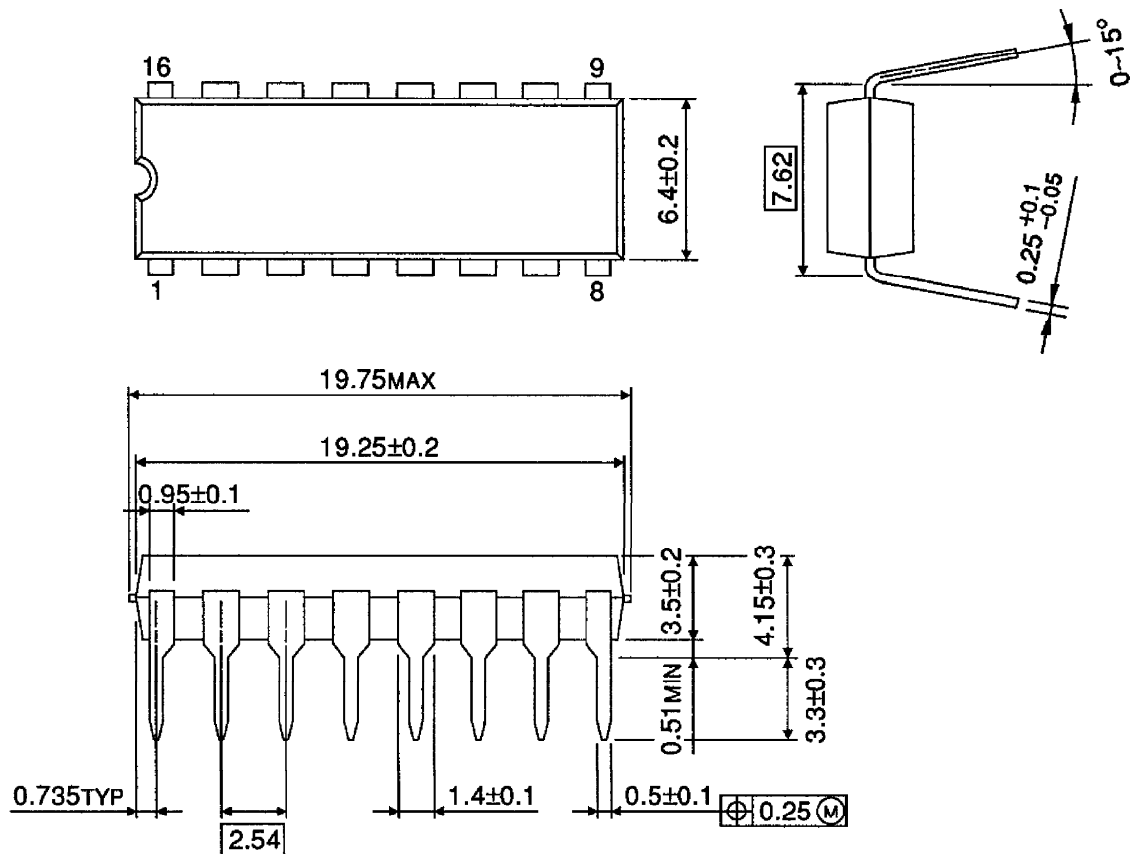
PRECAUTIONS for USING

Utmost care is necessary in the design of the output line, V_{CC} and GND (SUB, V_{EE}) line since IC may be destroyed due to short-circuit between outputs, air contamination fault, or fault by improper grounding.



OUTLINE DRAWING
DIP16-P-300-2.54A

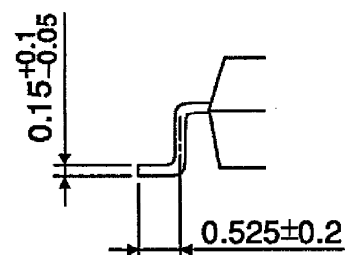
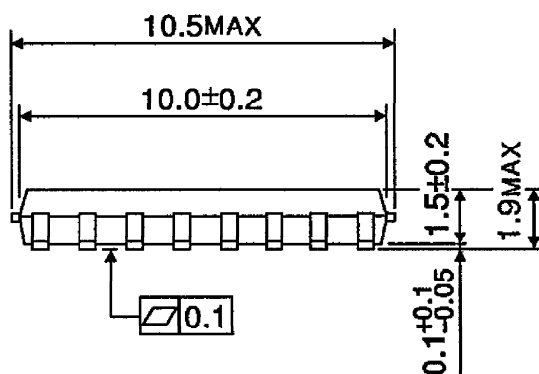
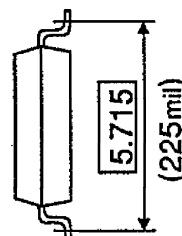
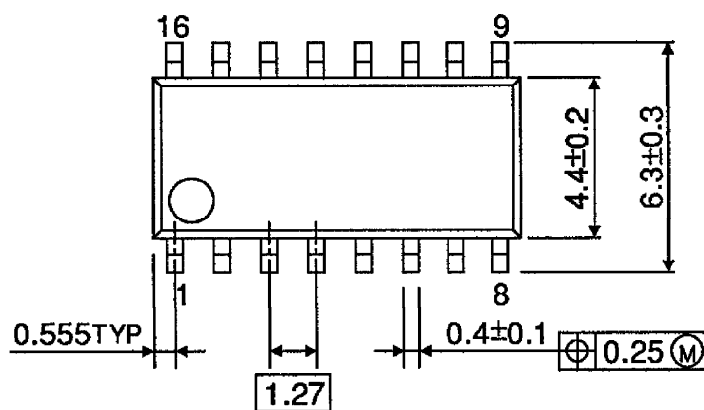
Unit : mm



Weight : 1.11g (Typ.)

OUTLINE DRAWING
SOP16-P-225-1.27

Unit : mm



Weight : 0.16g (Typ.)